**New Product** 



Reivision: 19-Apr-11

Vishay General Semiconductor

# Surface Mount Schottky Barrier Rectifier



DO-214AC (SMA)

### **FEATURES**

- · Low profile package
- · Ideal for automated placement
- · Guardring for overvoltage protection
- Low power losses, high efficiency
- · Very low switching losses
- High surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

#### **TYPICAL APPLICATIONS**

For use in high frequency inverters, switching power supplies, freewheeling diodes, oring diode, DC/DC converters and reverse battery protection.

### **MECHANICAL DATA**

Case: DO-214AC (SMA)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: Color band denotes the cathode end

| <b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)         |        |                                   |               |      |  |
|--|--------|-----------------------------------|---------------|------|--|
| PARAMETER  |        | SYMBOL                            | BYS11-90      | UNIT |  |
| Device marking code  |        |                                   | BYS109        |      |  |
| Maximum repetitive peak reverse voltage  |        | V <sub>RRM</sub>                  | 90            | V    |  |
| Maximum average forward rectified current                                      |        | I <sub>F(AV)</sub>                | 1.5           | А    |  |
| Peak forward surge current single half sine-wave<br>superimposed on rated load | 8.3 ms | I <sub>FSM</sub>                  | 40            | ^    |  |
|  | 10 ms  |                                   | 30            | - A  |  |
| Voltage rate of change (rated V <sub>R</sub> )                                 |        | dV/dt                             | 10 000        | V/µs |  |
| Junction and storage temperature range   |        | T <sub>J</sub> , T <sub>STG</sub> | - 55 to + 150 | °C   |  |

Document Number: 89409 For technical questions within your region, please contact one of the following: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com

RoHS COMPLIANT HALOGEN FREE

| PRIMARY CHARACTERISTICS |        |  |  |  |
|-------------------------|--------|--|--|--|
| I <sub>F(AV)</sub>      | 1.5 A  |  |  |  |
| V <sub>RRM</sub>        | 90 V   |  |  |  |
| I <sub>FSM</sub>        | 40 A   |  |  |  |
| V <sub>F</sub>          | 0.75 V |  |  |  |
| T <sub>J</sub> max.     | 150 °C |  |  |  |

# **BYS11-90**





| ELECTRICAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted) |                  |                         |                               |     |                               |          |      |
|--|------------------|-------------------------|-------------------------------|-----|-------------------------------|----------|------|
| PARAMETER  | TEST CONDITIONS  |                         | TEST CONDITIONS               |     | SYMBOL                        | BYS11-90 | UNIT |
| Maximum instantaneous forward voltage                                      | 1.0 A            |                         | forward voltage 1.0 A         |     | V <sub>F</sub> <sup>(1)</sup> | 750      | mV   |
| Maximum DC reverse current   | M                | T <sub>J</sub> = 25 °C  | I <sub>B</sub> <sup>(1)</sup> | 100 | μA                            |          |      |
|  | V <sub>RRM</sub> | T <sub>J</sub> = 100 °C | IR                            | 1   | mA                            |          |      |

#### Note

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

| <b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted) |                                 |          |      |  |
|--|---------------------------------|----------|------|--|
| PARAMETER  |                                 | BYS11-90 | UNIT |  |
| Maximum thermal resistance, junction to lead                                   |                                 | 25       | °C/W |  |
|  | R <sub>0JA</sub> <sup>(1)</sup> | 150      |      |  |
| Maximum thermal resistance, junction to ambient                                | R <sub>0JA</sub> <sup>(2)</sup> | 125      | °C/W |  |
|  | R <sub>0JA</sub> <sup>(3)</sup> | 100      |      |  |

#### Notes

<sup>(1)</sup> Mounted on epoxy-glass hard tissue

 $^{(2)}\,$  Mounted on epoxy-glass hard tissue, 50 mm^2 35  $\mu m$  Cu

<sup>(3)</sup> Mounted on Al-oxide-ceramic (Al<sub>2</sub>O<sub>3</sub>), 50 mm<sup>2</sup> 35 µm Cu

| ORDERING INFORMATION (Example) |                 |                        |               |                                    |  |  |
|--------------------------------|-----------------|------------------------|---------------|------------------------------------|--|--|
| PREFERRED P/N                  | UNIT WEIGHT (g) | PREFERRED PACKAGE CODE | BASE QUANTITY | DELIVERY MODE                      |  |  |
| BYS11-90-M3/TR                 | 0.064           | TR                     | 1800          | 7" diameter plastic tape and reel  |  |  |
| BYS11-90-M3/TR3                | 0.064           | TR3                    | 7500          | 13" diameter plastic tape and reel |  |  |

### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

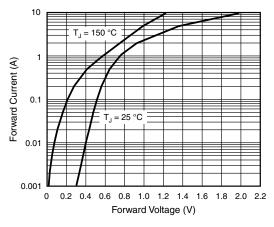


Fig. 1 - Forward Current vs. Forward Voltage

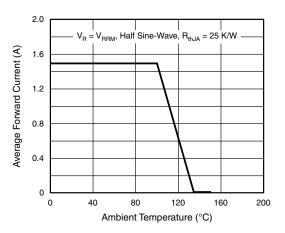


Fig. 2 - Max. Average Forward Current vs. Ambient Temperature

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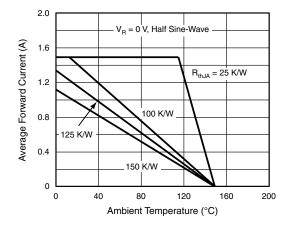


Fig. 3 - Max. Average Forward Current vs. Ambient Temperature

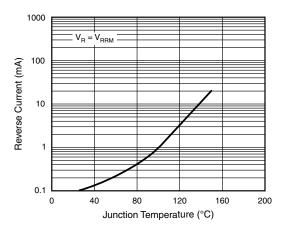


Fig. 4 - Reverse Current vs. Junction Temperature

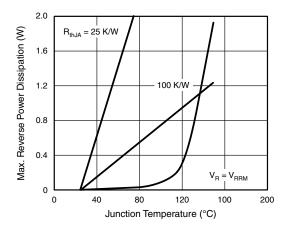


Fig. 5 - Max. Reverse Power Dissipation vs. Junction Temperature

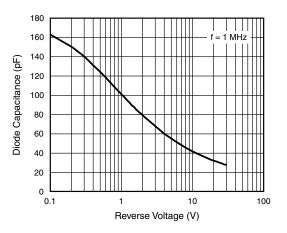
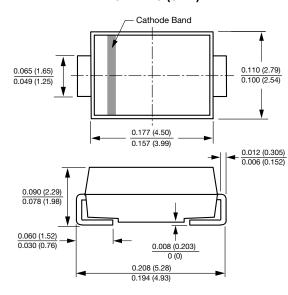


Fig. 6 - Diode Capacitance vs. Reverse Voltage

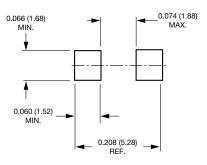


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#### PACKAGE OUTLINE DIMENSIONS in inches (millimeters) DO-214AC (SMA)



#### Mounting Pad Layout





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